


[Home](#) > [2N4863 \(#23222\)](#)

2N4863 (#23222)

Products

- ▶ [Product Directory](#)
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- ▶ [Parametric Search](#)

Overview

Diagrams

Electrical Rating	Symbol	Min	Typ	Max	Unit
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$			0.20	V
DC Current Gain	HFE	50.00		150.00	

Maximum Electrical Rating	Symbol	Min	Typ	Max	Unit
Breakdown Voltage, Collector-Base (Emitter Open)	$V_{BR(CBO)}$			140.00	V
Collector Current (dc)	I_C			2.00	A
Collector-Emitter Voltage (Base Open)	V_{CEO}			120.00	V
Emitter-Base Voltage (Collector Open)	V_{EBO}			8.00	V
Power Dissipation, Total	P_T			7.00	W

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